

## HIGH VOLTAGE SURFACE MOUNT SWITCHING DIODE

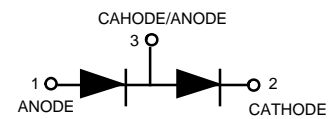
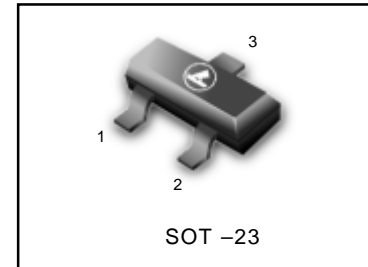
### FETURE

- Fast Switching Speed
- High Conductance
- High Reverse Breakdown Voltage Rating
- We declare that the material of product compliance with RoHS requirements.

### Ordering Information(Pb-free)

Device	Marking	Shipping
LMBD3004SLT1G	KAE	3000/Tape&Reel
LMBD3004SLT3G	KAE	10000/Tape&Reel

### LMBD3004SLT1G



### Maximum Ratings @ TA=25°C unless otherwise specified

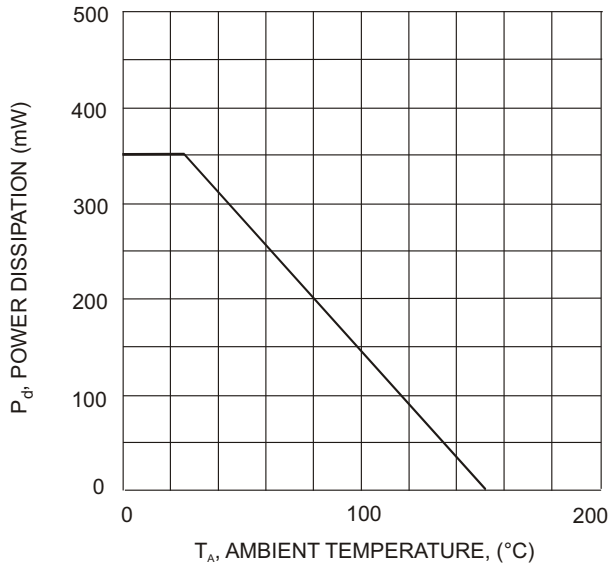
Characteristic	Symbol	LMC10114L	Unit
Repetitive Peak Reverse Voltage	VRRM	350	V
Working Peak Reverse Voltage	VRWM	300	V
DC Blocking Voltage	VR		
RMS Reverse Voltage	VR(RMS)	212	V
Forward Continuous Current(Note 2)	IF	225	mA
Peak Repetitive Forward Current(Note 2)	IFRM	625	mA
Non-Repetitive Peak Forward Surge Current	IFSM	@t=1.0μs	4.0
		@t=1.0s	1.0
Power Dissipation(Note 2)	Pd	350	mW
Thermal Resistance Junction to Ambient Air(Note 2)	RθJA	357	°C/W
Operating and Storage Temperature Range	Tj, TSTG	-65 to +150	°C

### Electrical Characteristics @ TA=25°C unless otherwise specified, per element

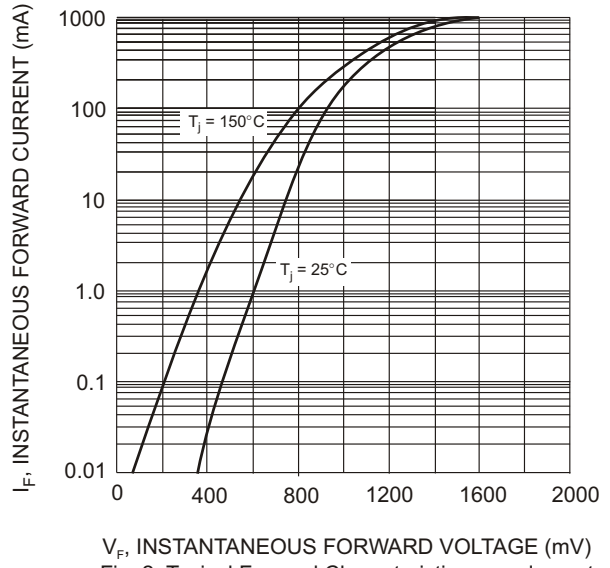
Characteristic	Symbol	Min	Typ	MAX	Unit	Test Condition
Reverse Breakdown Voltage(Note 1)	V(BR)R	350			V	IR=100μA
Forward Voltage(Note 1)	VF		0.78	0.87	V	IF=20mA
			0.93	1.0		IF=100mA
			1.03	1.25		IF=200mA
Reverse Current(Note 1)	IR		30	100	nA	VR=240V
			35	100	μA	VR=240V, Tj=150°C
Total Capacitance	CT		1.0	5.0	Pf	VR=0V, f=1.0MHZ
Reverse Recovery Time	Trr			50	ns	IF=IR=30mA Irr=3.0mA, RL=100Ω

- Notes: 1. Short duration test pulse used to minimize self-heating effect.  
2. Part mounted on FR-4 board with recommended pad layout.

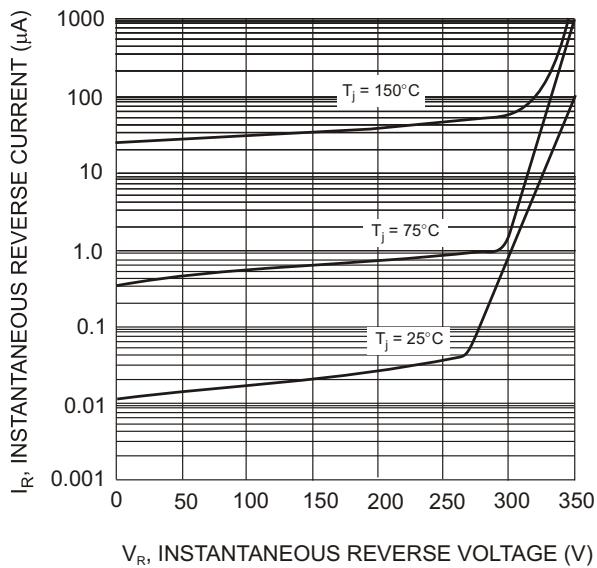
**LMBD3004SLT1G**



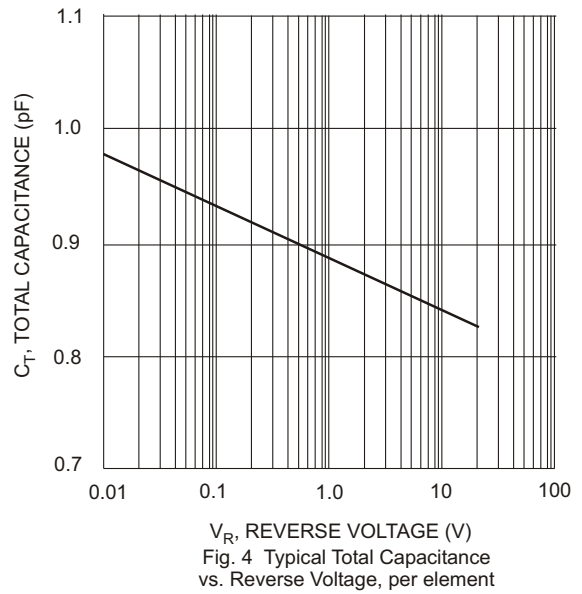
T<sub>A</sub>, AMBIENT TEMPERATURE, (°C)  
Fig. 1 Power Derating Curve, total package



V<sub>F</sub>, INSTANTANEOUS FORWARD VOLTAGE (mV)  
Fig. 2 Typical Forward Characteristics, per element



V<sub>R</sub>, INSTANTANEOUS REVERSE VOLTAGE (V)  
Fig. 3 Typical Reverse Characteristics, per element



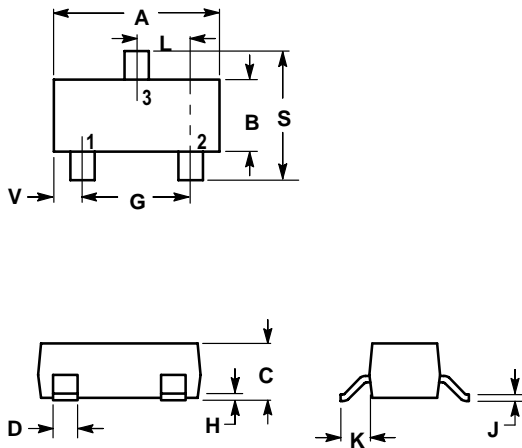
V<sub>R</sub>, REVERSE VOLTAGE (V)  
Fig. 4 Typical Total Capacitance vs. Reverse Voltage, per element

**LMBD3004SLT1G**

**SOT-23**

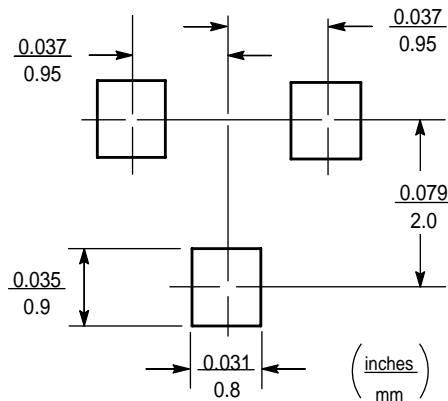
**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.

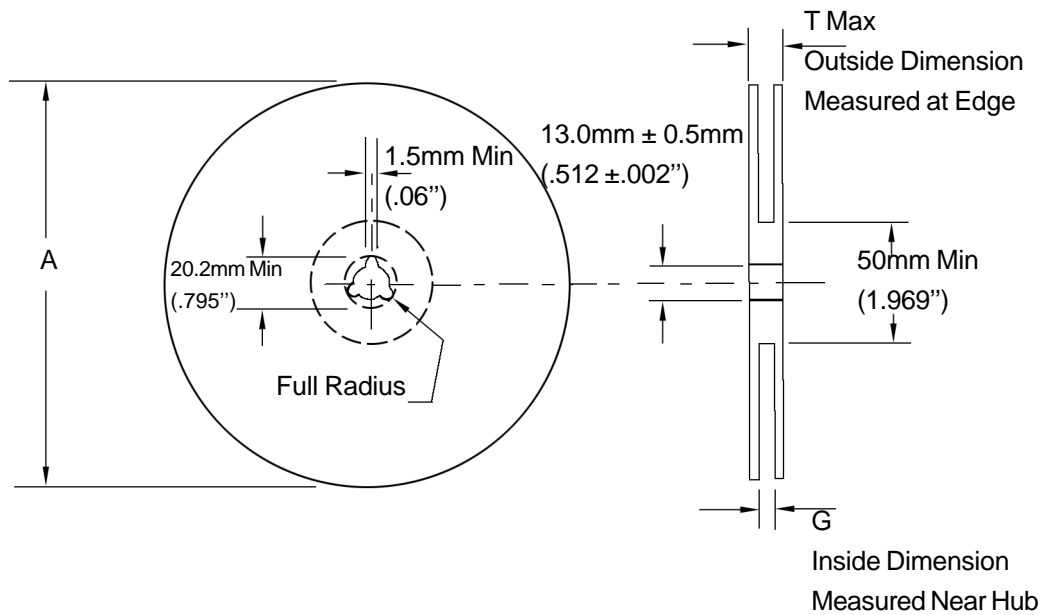


DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

- PIN 1. BASE
- 2. EMITTER
- 3. COLLECTOR



## EMBOSSED TAPE AND REEL DATA FOR DISCRETES



Size	A Max	G	T Max
8 mm	330mm (12.992")	8.4mm+1.5mm, -0.0 (.33"+.059", -0.00)	14.4mm (.56")

### Reel Dimensions

Metric Dimensions Govern — English are in parentheses for reference only

#### Storage Conditions

Temperature: 5 to 40 Deg.C (20 to 30 Deg. C is preferred)

Humidity: 30 to 80 RH (40 to 60 is preferred )

Recommended Period: One year after manufacturing

(This recommended period is for the soldering condition only. The characteristics and reliabilities of the products are not restricted to this limitation)

## Shipment Specification

